





EH49 45

Series —
RoHS Compliant (Pb-free) 1.8V 4 Pad 2.5mm x 3.2mm
Ceramic SMD LVCMOS Oscillator

Frequency Tolerance/Stability ±50ppm Maximum

Operating Temperature Range - 0°C to +70°C

TS -10.000M

Nominal Frequency 10.000MHz

Pin 1 Connection
Tri-State (High Impedance)

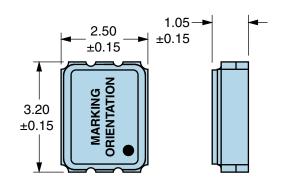
- Duty Cycle 50 ±10(%)

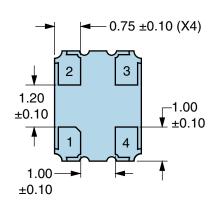
Frequency Tolerance/Stability       ±50ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°, 260°C Reflow, Shock, and Vibration)         Aging at 25°C       ±5ppm/Year Maximum         Operating Temperature Range       0°C to +70°C         Supply Voltage       1.8Vdc ±5%         Input Current       3.5mA Maximum (No Load)         Output Voltage Logic High (Voh)       90% of Vdd Minimum (IOH = -8mA)         Output Voltage Logic Low (Vol)       10% of Vdd Maximum (IOL = +8mA)         Rise/Fall Time       6nSec Maximum (Measured at 20% to 80% of waveform)         Duty Cycle       50 ±10(%) (Measured at 50% of waveform)         Load Drive Capability       15pF Maximum         Output Logic Type       CMOS         Pin 1 Connection       Tri-State (High Impedance)         Tri-State Input Voltage (Vih and Vil)       90% of Vdd Minimum or No Connect to Enable Output, 10% of Vdd Maximum to Disable Output (High Impedance)         Standby Current       10µA Maximum (Pin 1 = Ground)         Absolute Clock Jitter       ±125pSec Maximum         Start Up Time       10mSec Maximum	ELECTRICAL SPECIFICATIONS		
Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°, 260°C Reflow, Shock, and Vibration)         Aging at 25°C       ±5ppm/Year Maximum         Operating Temperature Range       0°C to +70°C         Supply Voltage       1.8Vdc ±5%         Input Current       3.5mA Maximum (No Load)         Output Voltage Logic High (Voh)       90% of Vdd Minimum (IOH = -8mA)         Output Voltage Logic Low (Vol)       10% of Vdd Maximum (IOL = +8mA)         Rise/Fall Time       6nSec Maximum (Measured at 20% to 80% of waveform)         Duty Cycle       50 ±10(%) (Measured at 50% of waveform)         Load Drive Capability       15pF Maximum         Output Logic Type       CMOS         Pin 1 Connection       Tri-State (High Impedance)         Tri-State Input Voltage (Vih and Vil)       90% of Vdd Minimum or No Connect to Enable Output, 10% of Vdd Maximum to Disable Output (High Impedance)         Standby Current       10µA Maximum (Pin 1 = Ground)         Absolute Clock Jitter       ±125pSec Maximum         Start Up Time       10mSec Maximum	Nominal Frequency	10.000MHz	
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Start Up Time 10mSec Maximum	Standby Current	10μA Maximum (Pin 1 = Ground)	
	Absolute Clock Jitter	±125pSec Maximum	
Storage Temperature Range -55°C to +125°C	Start Up Time	10mSec Maximum	
The state of the s	Storage Temperature Range	-55°C to +125°C	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
ESD Susceptibility	MIL-STD-883, Method 3015, Class 1, HBM: 1500Vdc	
Fine Leak Test	MIL-STD-883, Method 1014, Condition A	
Flammability	UL94-V0	
Gross Leak Test	MIL-STD-883, Method 1014, Condition C	
Mechanical Shock	MIL-STD-883, Method 2002, Condition B	
Moisture Resistance	MIL-STD-883, Method 1004	
Moisture Sensitivity	J-STD-020, MSL 1	
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, Method 1010, Condition B	
Vibration	MIL-STD-883, Method 2007, Condition A	



### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**



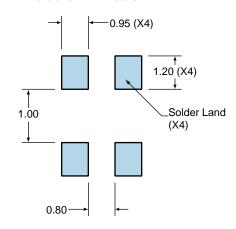


PIN	CONNECTION
1	Tri-State
2	Case Ground
3	Output
4	Supply Voltage

LINE	MARKING
1	EPO
_	XXXXX XXXXX=Ecliptek Manufacturing Identifier

### **Suggested Solder Pad Layout**

All Dimensions in Millimeters



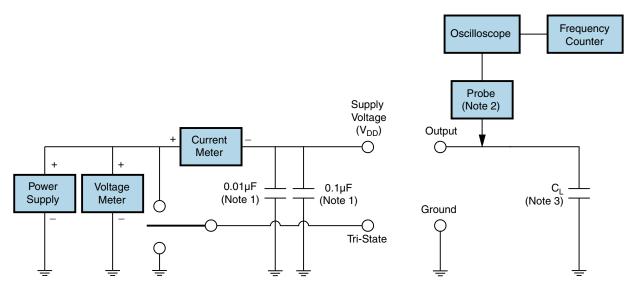
All Tolerances are ±0.1



#### **OUTPUT WAVEFORM & TIMING DIAGRAM**



#### **Test Circuit for CMOS Output**



- Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value C<sub>1</sub> includes sum of all probe and fixture capacitance.



## **Recommended Solder Reflow Methods**



### **High Temperature Infrared/Convection**

T <sub>s</sub> MAX to T <sub>∟</sub> (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	150°C
- Temperature Typical (T <sub>s</sub> TYP)	175°C
- Temperature Maximum (T <sub>S</sub> MAX)	200°C
- Time (t <sub>s</sub> MIN)	60 - 180 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T <sub>P</sub> )	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T <sub>P</sub> Target)	250°C +0/-5°C
Time within 5°C of actual peak (t <sub>p</sub> )	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



## **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 240°C

T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	N/A
- Temperature Typical (T <sub>S</sub> TYP)	150°C
- Temperature Maximum (T <sub>s</sub> MAX)	N/A
- Time (t <sub>s</sub> MIN)	60 - 120 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	240°C Maximum
Target Peak Temperature (T <sub>P</sub> Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

#### **Low Temperature Manual Soldering**

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.